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[Continued on next page]

(54) **Title:** SEMICONDUCTOR WAFER HAVING SCRIBE LANE ALIGNMENT MARKS FOR REDUCING CRACK PROPAGATION

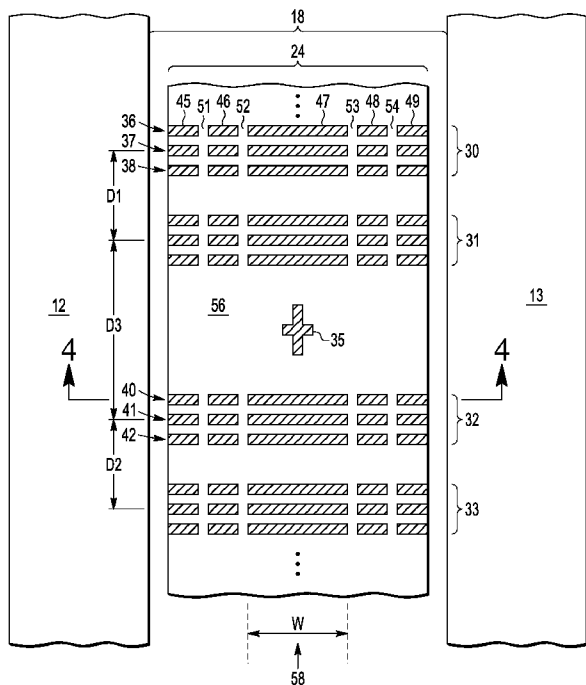


FIG. 2

(57) **Abstract:** A wafer (10) including at least a first die (12) and at least a second die (13), wherein the first die and the second die are separated from each other by an area located between the first die and the second die, is provided. The wafer further includes an alignment mark group (31) used for aligning the wafer to a tool used for patterning the wafer (10). The alignment mark group (31) is located entirely within the area between the first die (12) and the second die (13) and the alignment mark group includes a plurality of alignment lines (36, 37, 38), and wherein each line of the plurality of alignment lines is formed using a plurality of segments (45, 46, 47, 48, 49) separated from each other by a plurality of gaps (51, 52, 53, 54) filled with an insulating material.

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## INTERNATIONAL SEARCH REPORT

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**PCT/US2010/049636****A. CLASSIFICATION OF SUBJECT MATTER****H01L 21/301(2006.01)i**

According to International Patent Classification (IPC) or to both national classification and IPC

**B. FIELDS SEARCHED**

Minimum documentation searched (classification system followed by classification symbols)

H01L 21/301; H01L 21/47; H01L 21/027; H01L 23/544; H01L 21/44

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Korean utility models and applications for utility models  
Japanese utility models and applications for utility models

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

eKOMPASS(KIPO internal) &amp; Keywords: wafer, alignment, mark, segment, gap

**C. DOCUMENTS CONSIDERED TO BE RELEVANT**

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	US 05525840 A (TOMINAGA; MAKOTO) 11 June 1996 See column 5, line 50-column 6, line 2;claim 1;figure 6.	1-20
A	US 2002-0094679 A1 (WON SONG et al.) 18 July 2002 See abstract;paragraphs [0034]-[0049];claim 1;figures 8A-8B,9A-9B.	1-20
A	US 04981529 A (TSUJITA; KOUICHIROU) 01 January 1991 See column 6, lines 30-59;claim 1;figure 1.	1-20
A	KR 10-2003-0041015 A (HYNIX SEMICONDUCTOR INC.) 23 May 2003 See abstract;page 3;claim 1;figures 3-9.	1-20

 Further documents are listed in the continuation of Box C. See patent family annex.

\* Special categories of cited documents:

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"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art

"&amp;" document member of the same patent family

Date of the actual completion of the international search

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**INTERNATIONAL SEARCH REPORT**

Information on patent family members

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Patent document cited in search report	Publication date	Patent family member(s)	Publication date
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